

DATA SHEET

74LVU04 Hex inverter

Product specification
Supersedes data of 2000 Dec 18

2001 Jan 11

Hex inverter

74LVU04

FEATURES

- Wide operating voltage: 1.0 to 5.5 V
- Optimized for Low Voltage applications: 1.0 to 3.6 V
- Typical V_{OLP} (output ground bounce) < 0.8 V at $V_{CC} = 3.3$ V, $T_{amb} = 25$ °C.
- Typical V_{OHV} (output V_{OH} undershoot) > 2 V at $V_{CC} = 3.3$ V, $T_{amb} = 25$ °C.
- Output capability: standard
- I_{CC} category: SSI

DESCRIPTION

The 74LVU04 is a low-voltage, Si-gate CMOS device and is pin compatible with the 74HCU04.

The 74LVU04 is a general purpose hex inverter. Each of the six inverters is a single stage with unbuffered outputs.

QUICK REFERENCE DATA

$GND = 0$ V; $T_{amb} = 25$ °C; $t_r = t_f \leq 2.5$ ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	Propagation delay nA to nY	$C_L = 15$ pF; $V_{CC} = 3.3$ V	6	ns
C_I	Input capacitance		3.5	pF
C_{PD}	Power dissipation capacitance per gate	Notes 1, 2	18	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W)
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz; C_L = output load capacitance in pF;
 f_o = output frequency in MHz; V_{CC} = supply voltage in V;
 $\Sigma (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.
2. The condition is $V_I = GND$ to V_{CC} .

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-Pin Plastic DIL	-40 to +125 °C	74LVU04N	74LVU04N	SOT27-1
14-Pin Plastic SO	-40 to +125 °C	74LVU04D	74LVU04D	SOT108-1
14-Pin Plastic SSOP Type II	-40 to +125 °C	74LVU04DB	74LVU04DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40 to +125 °C	74LVU04PW	74LVU04PWDH	SOT402-1

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 3, 5, 9, 11, 13	1A – 6A	Data inputs
2, 4, 6, 8, 10, 12	1Y – 6Y	Data outputs
7	GND	Ground (0 V)
14	V_{CC}	Positive supply voltage

FUNCTION TABLE

INPUTS	OUTPUTS
nA	nY
L	H
H	L

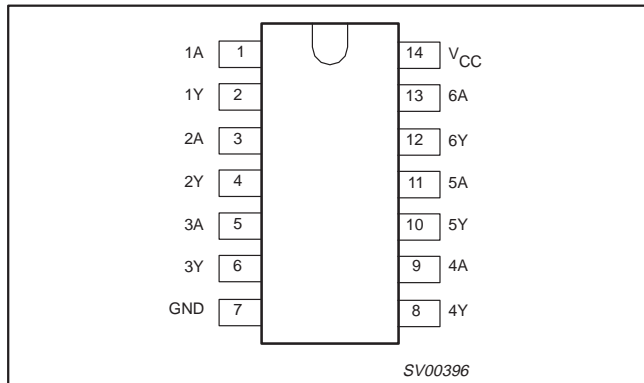
NOTES:

H = HIGH voltage level
L = LOW voltage level

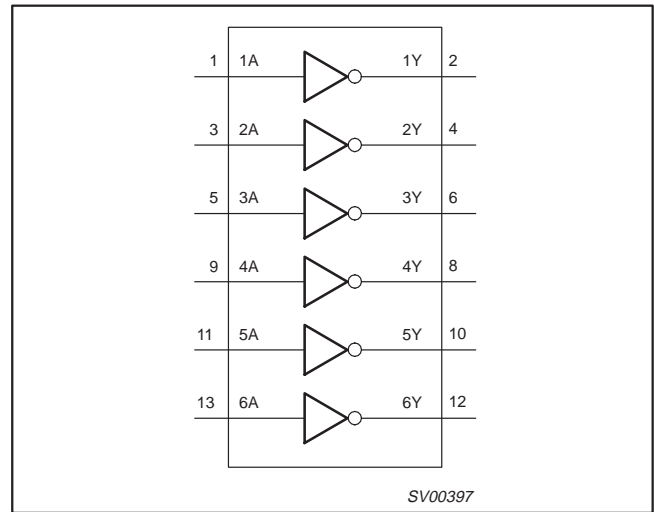
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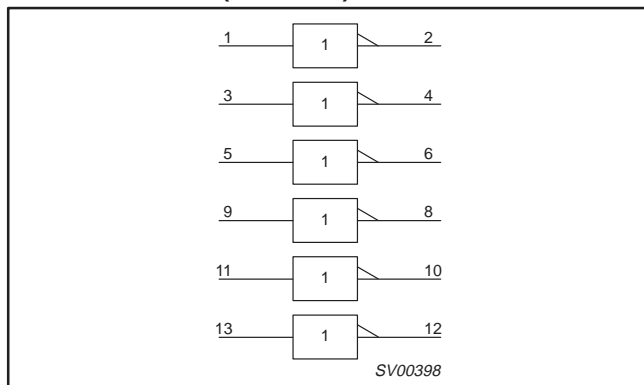
PIN CONFIGURATION



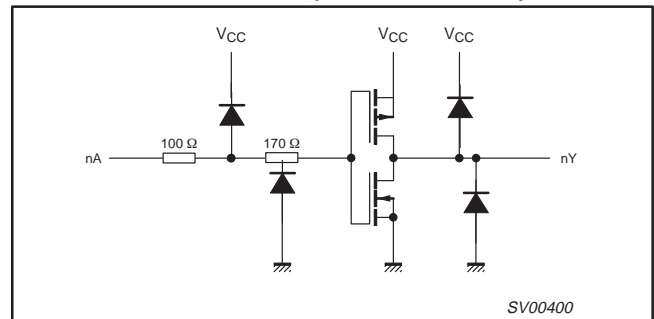
LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



SCHEMATIC DIAGRAM (ONE INVERTER)



RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V_{CC}	DC supply voltage	See Note 1	1.0	3.3	5.5	V
V_I	Input voltage		0	–	V_{CC}	V
V_O	Output voltage		0	–	V_{CC}	V
T_{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	–40		+85	°C
			–40		+125	
t_r, t_f	Input rise and fall times	$V_{CC} = 1.0$ to 2.0 V	–	–	500	ns/V
		$V_{CC} = 2.0$ to 2.7 V	–	–	200	
		$V_{CC} = 2.7$ to 3.6 V	–	–	100	
		$V_{CC} = 3.6$ to 5.5 V	–	–	50	

NOTE:

- The LV is guaranteed to function down to $V_{CC} = 1.0$ V (input levels GND or V_{CC}); DC characteristics are guaranteed from $V_{CC} = 1.2$ V to $V_{CC} = 5.5$ V.

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +7.0	V
$\pm I_{IK}$	DC input diode current	$V_I < -0.5$ or $V_I > V_{CC} + 0.5$ V	20	mA
$\pm I_{OK}$	DC output diode current	$V_O < -0.5$ or $V_O > V_{CC} + 0.5$ V	50	mA
$\pm I_O$	DC output source or sink current – standard outputs	-0.5 V < V_O < $V_{CC} + 0.5$ V	25	mA
$\pm I_{GND}$, $\pm I_{CC}$	DC V_{CC} or GND current for types with – standard outputs		50	mA
T_{stg}	Storage temperature range		-65 to +150	°C
P_{TOT}	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125 °C above +70 °C derate linearly with 12 mW/K above +70 °C derate linearly with 8 mW/K above +60 °C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			-40 to +85 °C			-40 to +125 °C		
			MIN	TYP ¹	MAX	MIN	MAX	
V_{IH}	HIGH level Input voltage	$V_{CC} = 1.2$ V	1.0			1.0		V
		$V_{CC} = 2.0$ V	1.6			1.6		
		$V_{CC} = 2.7$ to 3.6 V	2.4			2.4		
		$V_{CC} = 4.5$ to 5.5 V	$0.8 \cdot V_{CC}$			$0.8 \cdot V_{CC}$		
V_{IL}	LOW level Input voltage	$V_{CC} = 1.2$ V			0.2		0.2	V
		$V_{CC} = 2.0$ V			0.4		0.4	
		$V_{CC} = 2.7$ to 3.6 V			0.5		0.5	
		$V_{CC} = 4.5$ to 5.5 V			$0.2 \cdot V_{CC}$		$0.2 \cdot V_{CC}$	
V_{OH}	HIGH level output voltage	$V_{CC} = 1.2$ V; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100$ μ A		1.2				V
		$V_{CC} = 2.0$ V; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100$ μ A	1.8	2.0		1.8		
		$V_{CC} = 2.7$ V; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100$ μ A	2.5	2.7		2.5		
		$V_{CC} = 3.0$ V; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100$ μ A	2.8	3.0		2.8		
		$V_{CC} = 4.5$ V; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100$ μ A	4.3	4.5		4.3		
V_{OH}	HIGH level output voltage	$V_{CC} = 3.0$ V; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 6$ mA	2.40	2.82		2.20		V
		$V_{CC} = 4.5$ V; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 12$ mA	3.60	4.20		3.50		
V_{OL}	LOW level output voltage	$V_{CC} = 1.2$ V; $V_I = V_{IH}$ or V_{IL} ; $I_O = 100$ μ A		0				V
		$V_{CC} = 2.0$ V; $V_I = V_{IH}$ or V_{IL} ; $I_O = 100$ μ A		0	0.2		0.2	
		$V_{CC} = 2.7$ V; $V_I = V_{IH}$ or V_{IL} ; $I_O = 100$ μ A		0	0.2		0.2	
		$V_{CC} = 3.0$ V; $V_I = V_{IH}$ or V_{IL} ; $I_O = 100$ μ A		0	0.2		0.2	
		$V_{CC} = 4.5$ V; $V_I = V_{IH}$ or V_{IL} ; $I_O = 100$ μ A		0	0.2		0.2	
V_{OL}	LOW level output voltage	$V_{CC} = 3.0$ V; $V_I = V_{IH}$ or V_{IL} ; $I_O = 6$ mA		0.25	0.40		0.50	V
		$V_{CC} = 4.5$ V; $V_I = V_{IH}$ or V_{IL} ; $I_O = 12$ mA		0.35	0.55		0.65	
$\pm I_I$	Input leakage current	$V_{CC} = 5.5$ V; $V_I = V_{CC}$ or GND			1.0		1.0	μ A
I_{CC}	Quiescent supply current	$V_{CC} = 5.5$ V; $V_I = V_{CC}$ or GND; $I_O = 0$			20.0		40.0	μ A

NOTE:

- All typical values are measured at $T_{amb} = 25$ °C.

Hex inverter

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AC CHARACTERISTICS

GND = 0 V; $t_r = t_f = 2.5$ ns; $C_L = 50$ pF; $R_L = 500 \Omega$

SYMBOL	PARAMETER	WAVEFORM	CONDITION	LIMITS				UNIT	
				-40 to +85 °C			-40 to +125 °C		
				MIN	TYP ¹	MAX	MIN		MAX
$t_{PHL/PLH}$	Propagation delay nA to nY	Figure 1	$V_{CC}(V)$					ns	
			1.2		35				
			2.0		12	14	17		
			2.7		9	10	13		
			3.0 to 3.6		7 ²	8	10		
4.5 to 5.5			7	9					

NOTES:

1. Unless otherwise stated, all typical values are measured at $T_{amb} = 25$ °C
2. Typical values are measured at $V_{CC} = 3.3$ V.

AC WAVEFORMS

$V_M = 1.5$ V at $V_{CC} \geq 2.7$ V and ≤ 3.6 V

$V_M = 0.5 \times V_{CC}$ at $V_{CC} < 2.7$ V and ≥ 4.5 V

V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

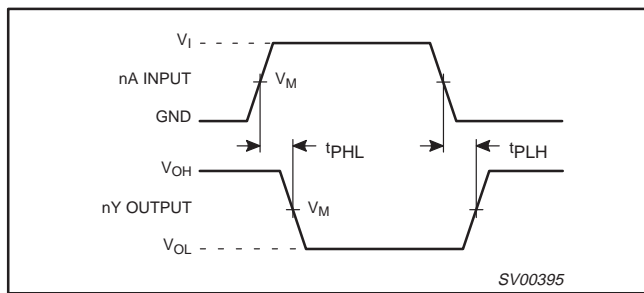


Figure 1. Input (nA) to output (nY) propagation delays and output transition times.

TYPICAL TRANSFER CHARACTERISTICS

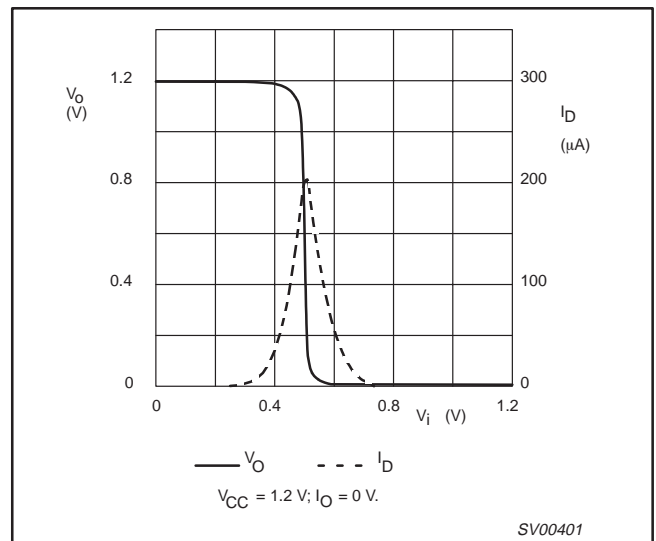


Figure 2.

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TYPICAL TRANSFER CHARACTERISTICS (Continued)

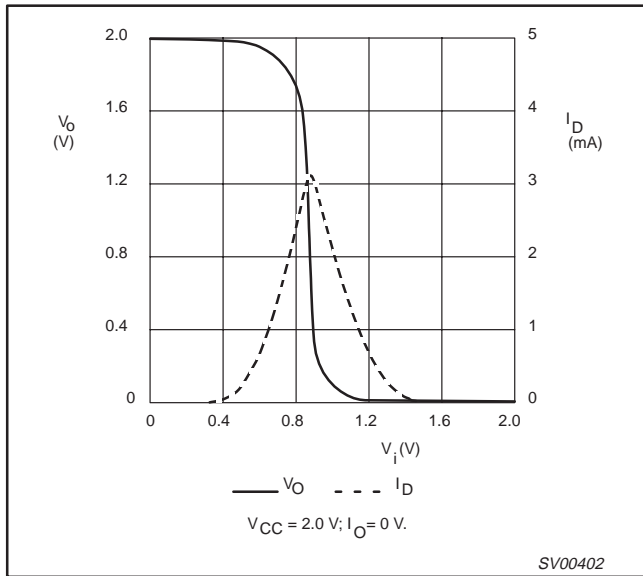


Figure 3.

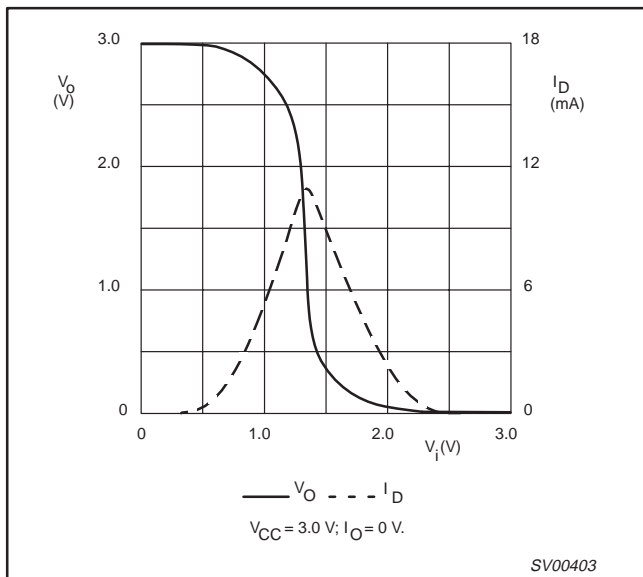


Figure 4.

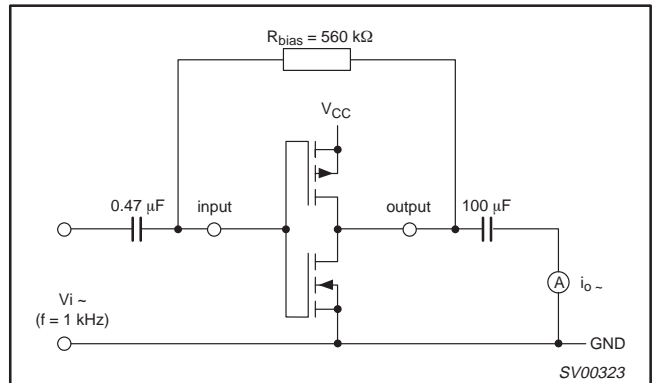


Figure 5. Test set-up for measuring forward transconductance $g_{fs} = di_o/dv_i$ at v_o is constant (see also graph Figure 6).

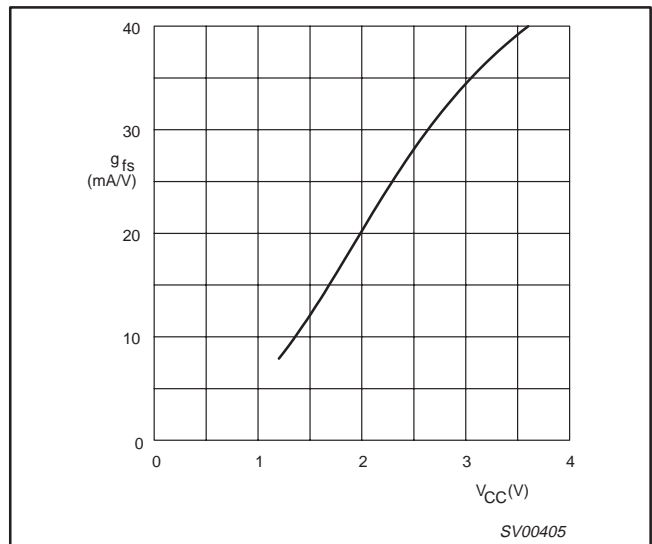


Figure 6. Typical forward transconductance g_{fs} as a function of the supply voltage V_{CC} at $T_{amb} = 25$ °C.

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APPLICATION INFORMATION

Some applications for the 74LVU04 are:

- Linear amplifier (see Figure 7)
- In crystal oscillator designs (see Figure 8)
- Astable multivibrator (see Figure 9)

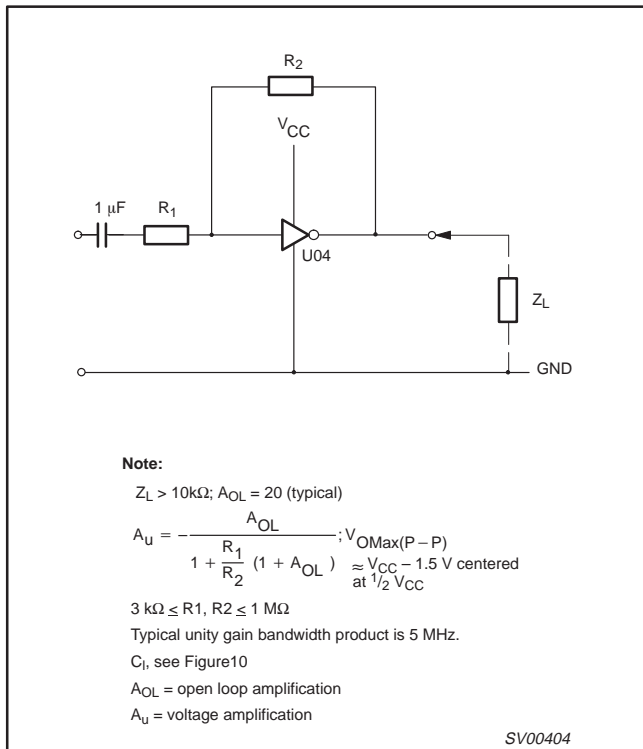


Figure 7. LVU04 used as a linear amplifier.

EXTERNAL COMPONENTS FOR RESONATOR (f < 1 MHz)

FREQUENCY (kHz)	R ₁ (MΩ)	R ₂ (kΩ)	C ₁ (pF)	C ₂ (pF)
10 .. 15.9	2.2	220	56	20
16 .. 24.9	2.2	220	56	10
25 .. 54.9	2.2	100	56	10
55 .. 129.9	2.2	100	47	5
130 .. 199.9	2.2	47	47	5
200 .. 349.9	2.2	47	47	5
350 .. 600	2.2	47	47	5

WHERE:

All values given are typical and must be used as an initial set-up.

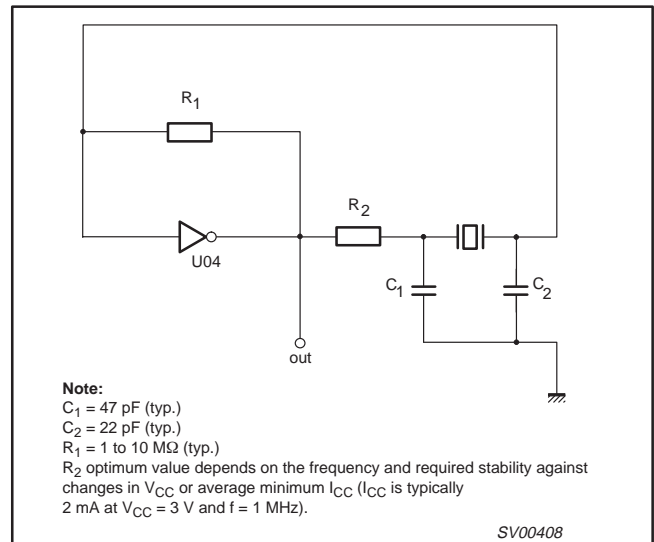


Figure 8. Crystal oscillator configuration.

OPTIMUM VALUE FOR R₂

FREQUENCY (MHz)	R ₂ (kΩ)	Optimum
3	2.0 8.0	Minimum required I_{CC} Minimum influence due to change in V_{CC}
6	1.0 4.7	Minimum I_{CC} Minimum influence by V_{CC}
10	0.5 2.0	Minimum I_{CC} Minimum influence by V_{CC}
14	0.5 1.0	Minimum I_{CC} Minimum influence by V_{CC}
> 14	Replace R_2 by C_3 with a typical value of 35 pF	

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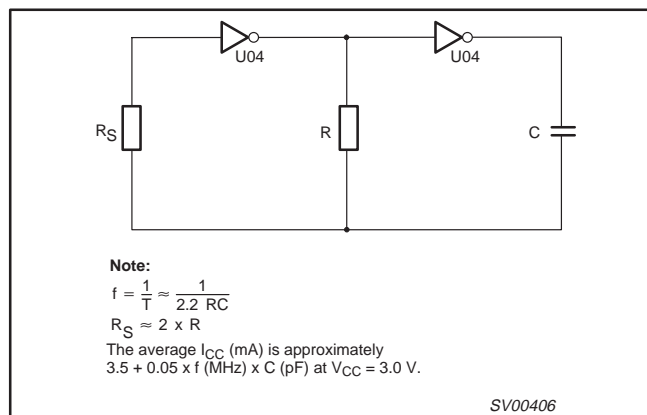


Figure 9. LVU04 used as an astable multivibrator.

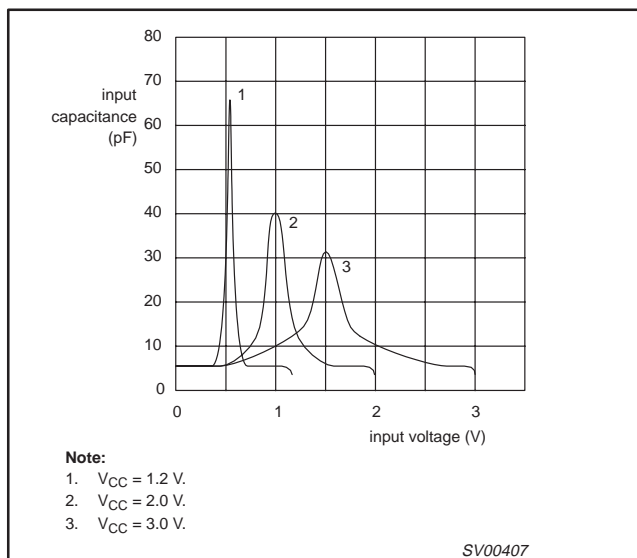


Figure 10. Typical input capacitance as function of input voltage.

Note for Application Information

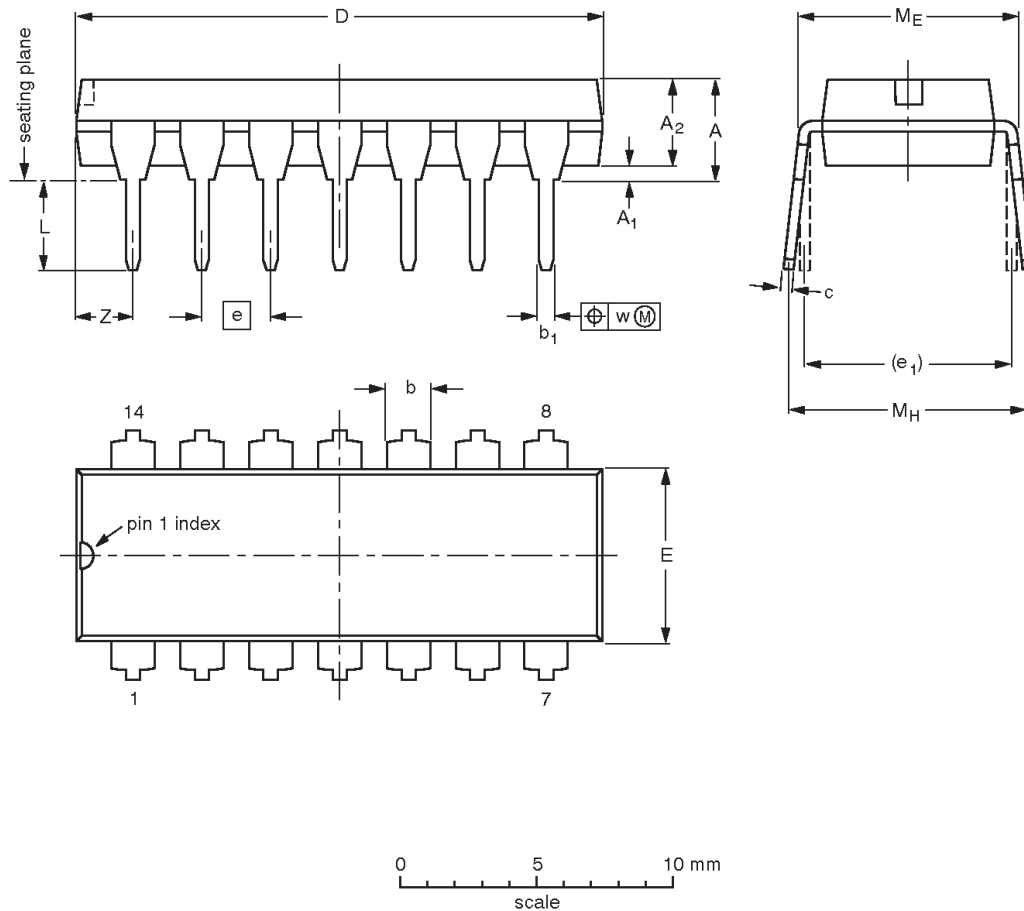
All values given are typical unless otherwise specified.

Hex inverter

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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

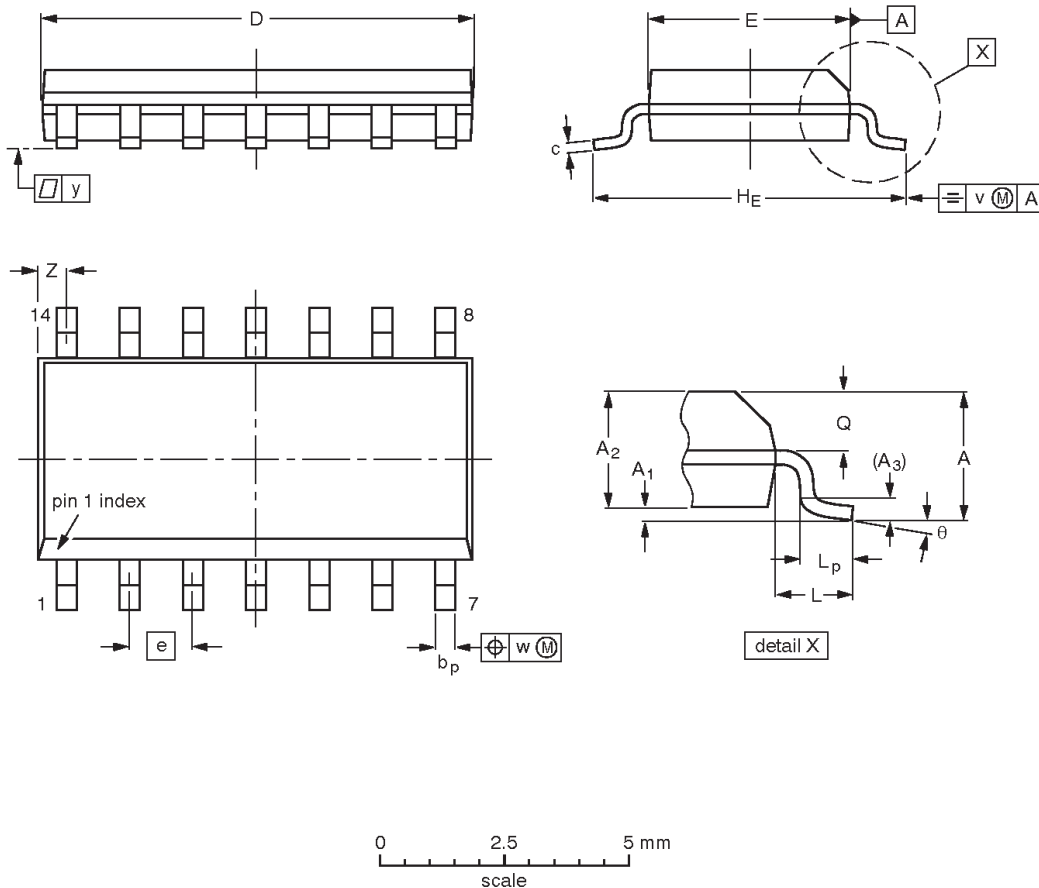
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT27-1	050G04	MO-001	SC-501-14			95-03-11 99-12-27

Hex inverter

74LVU04

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

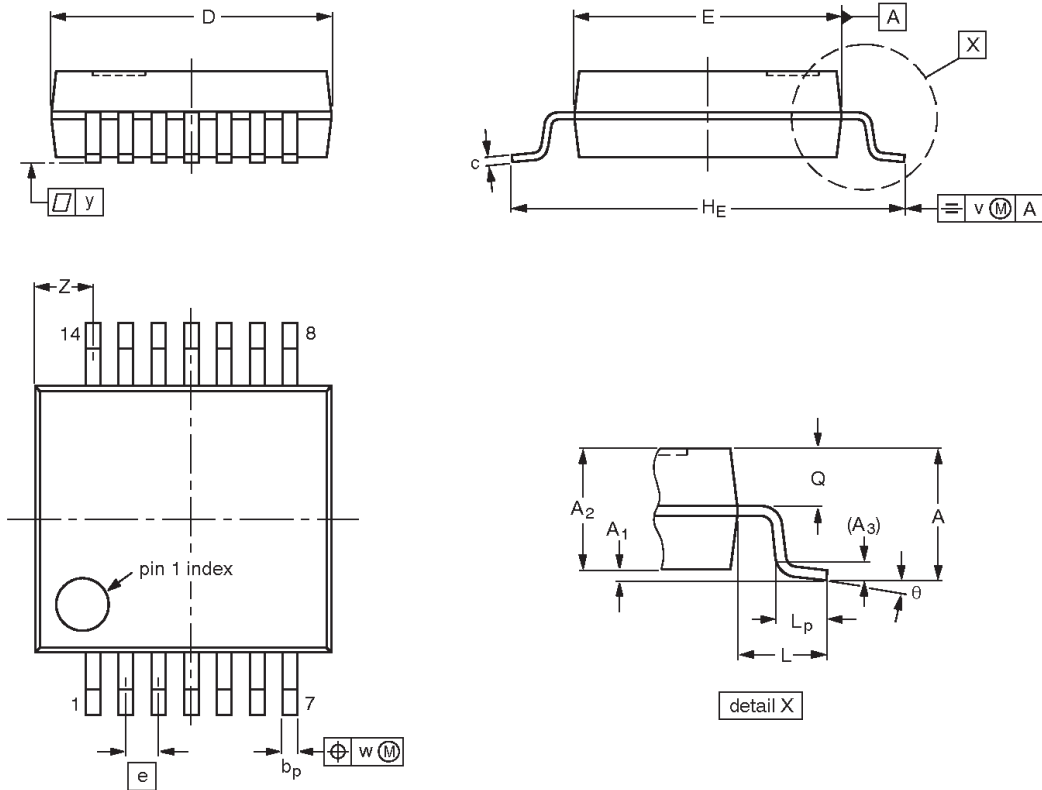
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT108-1	076E06	MS-012				97-05-22 99-12-27

Hex inverter

74LVU04

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

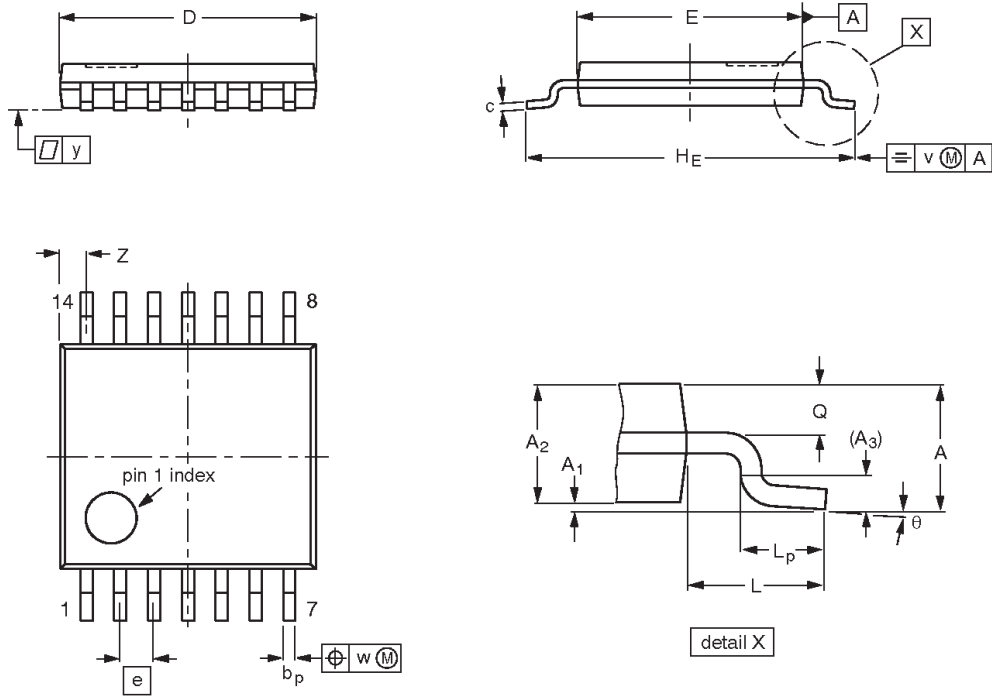
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT337-1		MO-150				96-01-18 99-12-27

Hex inverter

74LVU04

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT402-1		MO-153				-95-04-04 99-12-27

Hex inverter

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NOTES

Hex inverter

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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